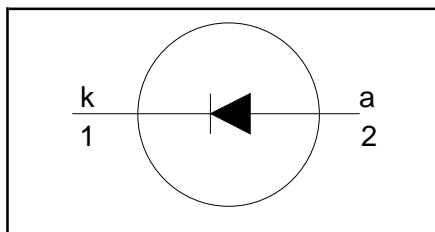


# Rectifier diode ultrafast, low switching loss

**BYC5-600****FEATURES**

- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

**SYMBOL****QUICK REFERENCE DATA**

$$V_R = 600 \text{ V}$$

$$V_F \leq 1.75 \text{ V}$$

$$I_{F(AV)} = 5 \text{ A}$$

$$t_{rr} = 19 \text{ ns (typ)}$$

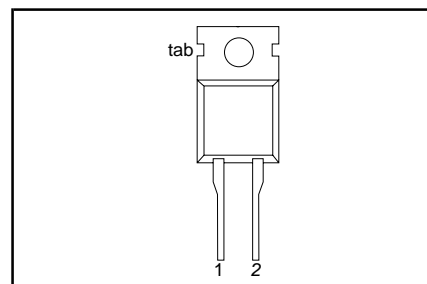
**APPLICATIONS**

- Active power factor correction
- Half-bridge lighting ballasts
- Half-bridge/ full-bridge switched mode power supplies.

The BYC5-600 is supplied in the SOD59 (TO220AC) conventional leaded package.

**PINNING**

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

**SOD59 (TO220AC)****LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	Peak repetitive reverse voltage	$T_{mb} \leq 110^\circ\text{C}$ $\delta = 0.5$ ; with reappplied $V_{RRM(max)}$ ; $T_{mb} \leq 89^\circ\text{C}$ $\delta = 0.5$ ; with reappplied $V_{RRM(max)}$ ; $T_{mb} \leq 89^\circ\text{C}$	-	600	V
$V_{RWM}$	Crest working reverse voltage		-	600	V
$V_R$	Continuous reverse voltage		-	500	V
$I_{F(AV)}$	Average forward current		-	5	A
$I_{FRM}$	Repetitive peak forward current		-	10	A
$I_{FSM}$	Non-repetitive peak forward current.	$t = 10 \text{ ms}$	-	40	A
		$t = 8.3 \text{ ms}$ sinusoidal; $T_j = 150^\circ\text{C}$ prior to surge with reappplied $V_{RWM(max)}$	-	44	A
$T_{stg}$	Storage temperature		-40	150	$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150	$^\circ\text{C}$

**THERMAL RESISTANCES**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	in free air.	-	-	2.5	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient		-	60	-	K/W

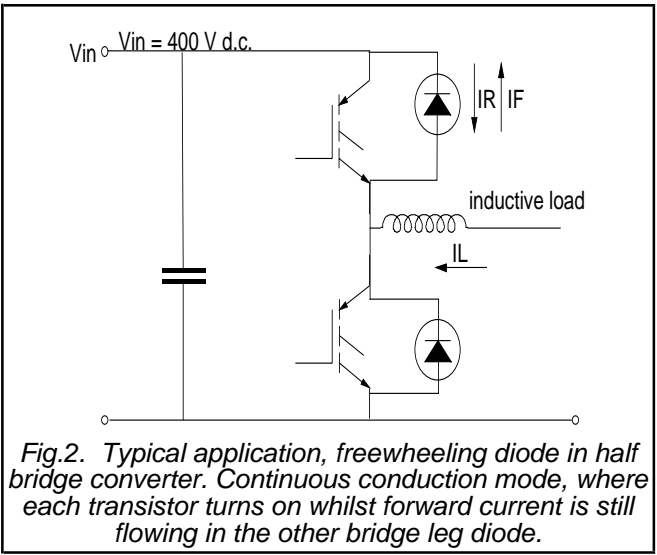
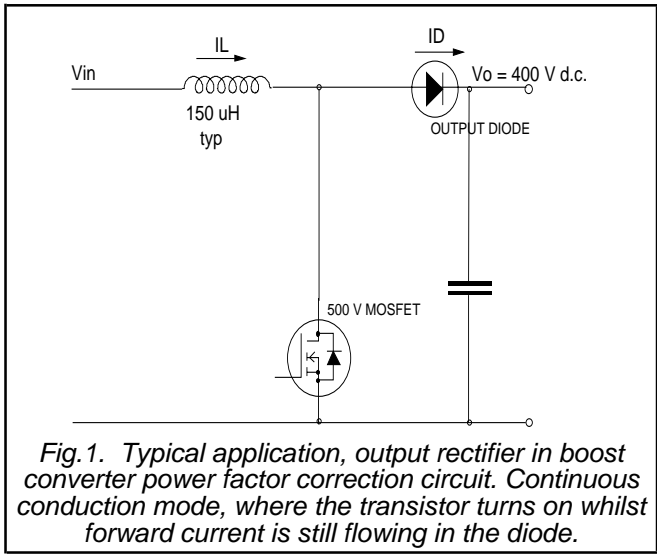
Rectifier diode  
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ELECTRICAL CHARACTERISTICS

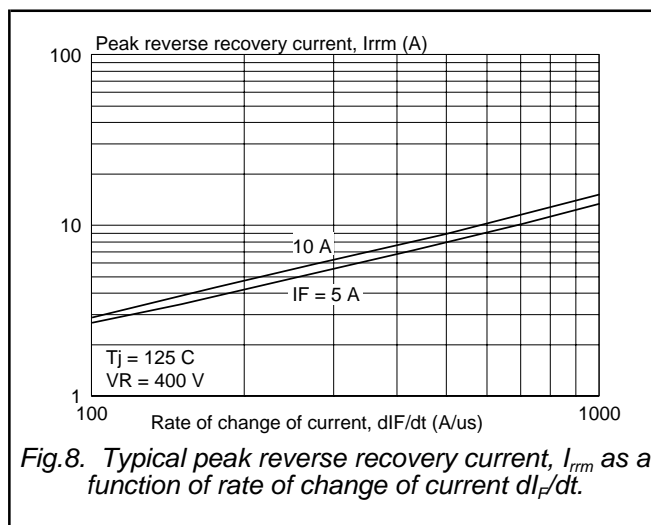
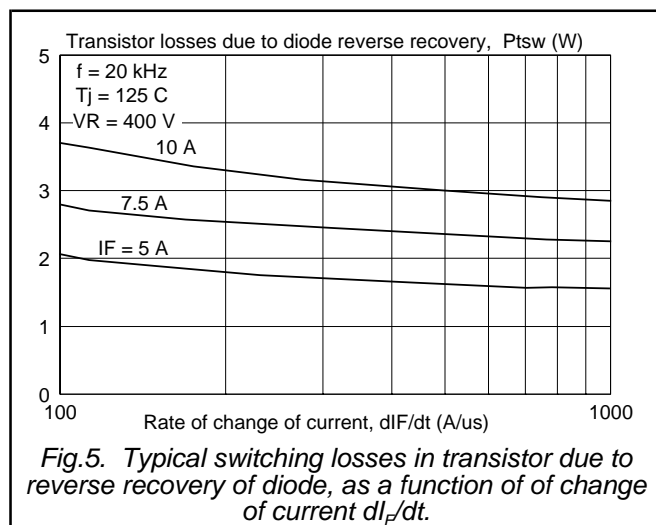
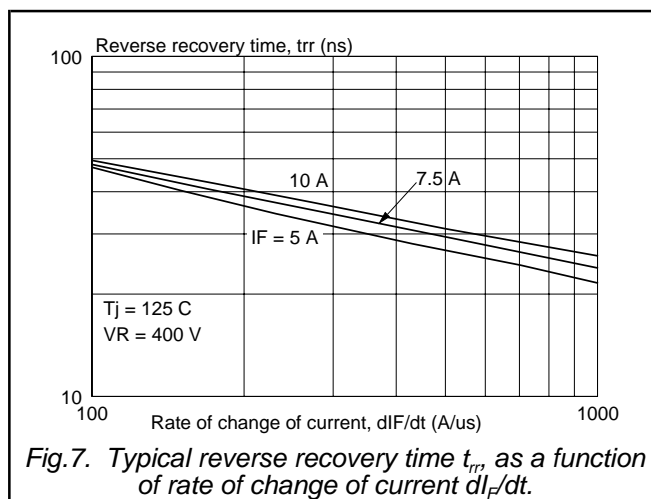
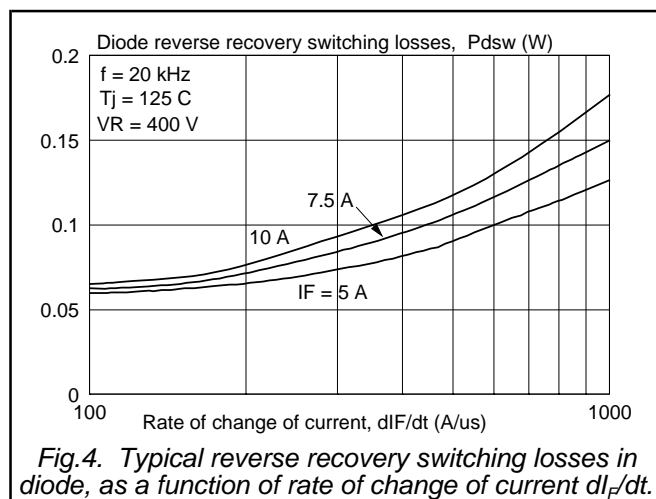
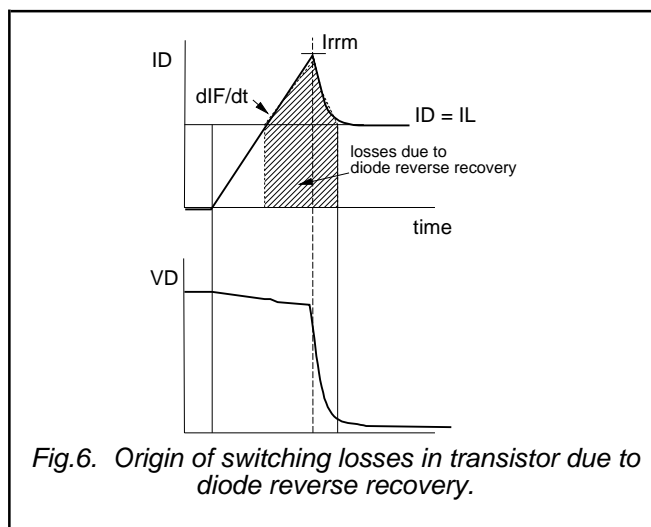
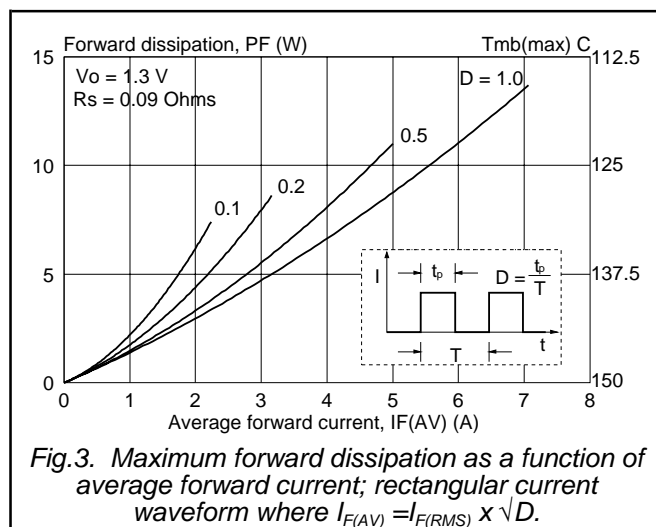
T<sub>j</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 5 A; T <sub>j</sub> = 150 °C	-	1.4	1.75	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 150 °C	-	1.75	2.2	V
I <sub>R</sub>	Reverse current	I <sub>F</sub> = 5 A;	-	2.0	2.9	V
		V <sub>R</sub> = 600 V	-	9	100	μA
		V <sub>R</sub> = 500 V; T <sub>j</sub> = 100 °C	-	0.9	3.0	mA
t <sub>rr</sub>	Reverse recovery time	I <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; dI <sub>F</sub> /dt = 50 A/μs	-	30	50	ns
t <sub>rr</sub>	Reverse recovery time	I <sub>F</sub> = 5 A; V <sub>R</sub> = 400 V;	-	19	-	ns
		dI <sub>F</sub> /dt = 500 A/μs	-			
t <sub>rr</sub>	Reverse recovery time	I <sub>F</sub> = 5 A; V <sub>R</sub> = 400 V;	-	25	30	ns
		dI <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 100 °C	-			
I <sub>rrm</sub>	Peak reverse recovery current	I <sub>F</sub> = 5 A; V <sub>R</sub> = 400 V;	-	0.7	3	A
		dI <sub>F</sub> /dt = 50 A/μs; T <sub>j</sub> = 125 °C	-			
I <sub>rrm</sub>	Peak reverse recovery current	I <sub>F</sub> = 5 A; V <sub>R</sub> = 400 V;	-	8	11	A
		dI <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 125 °C	-			
V <sub>fr</sub>	Forward recovery voltage	I <sub>F</sub> = 10 A; dI <sub>F</sub> /dt = 100 A/μs	-	9	11	V



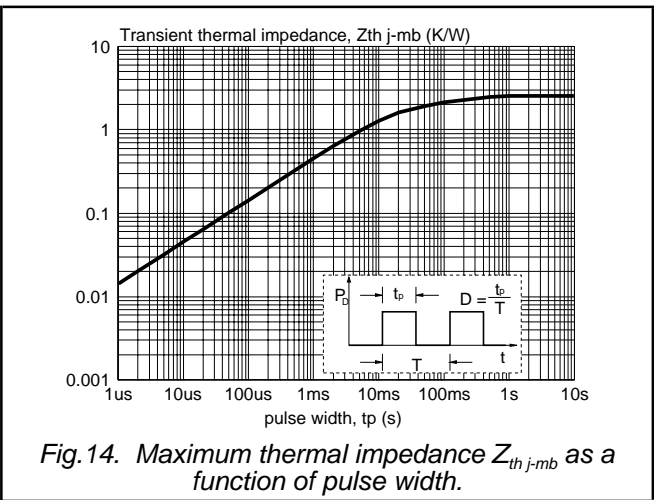
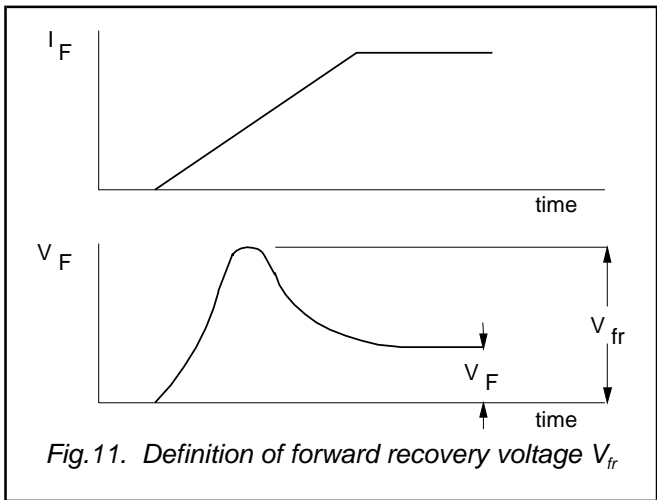
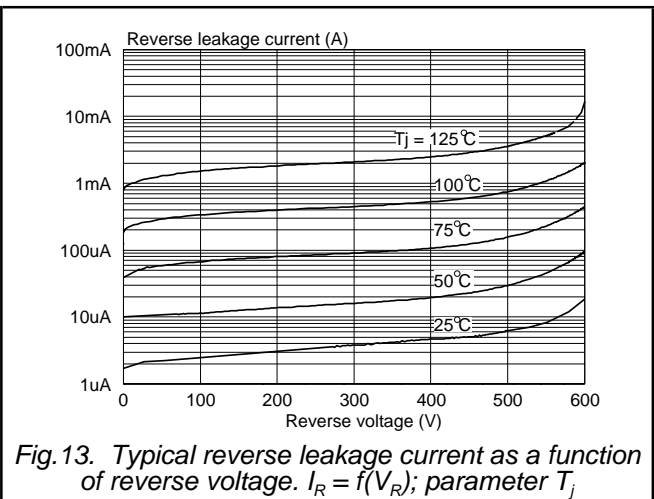
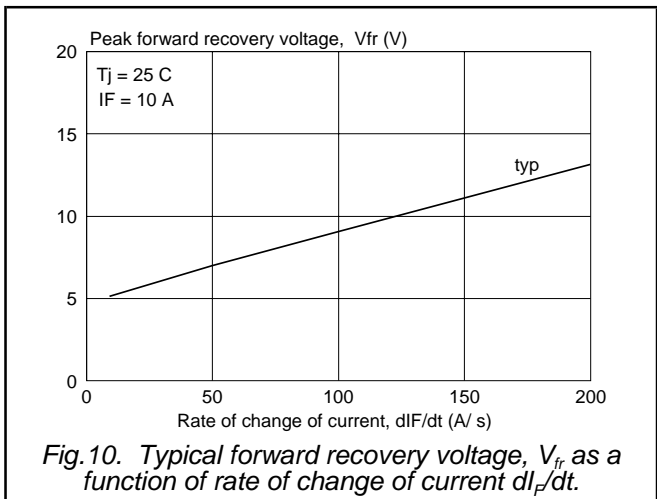
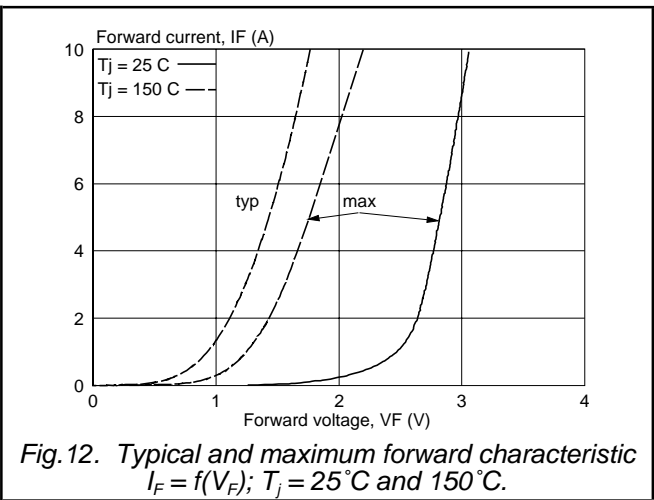
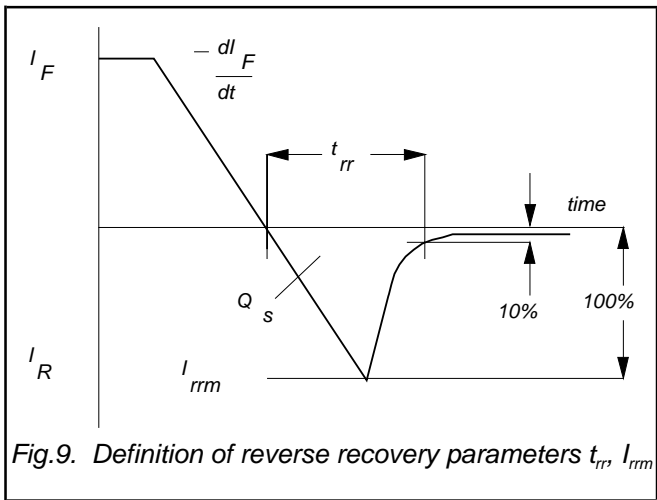
# Rectifier diode ultrafast, low switching loss

BYC5-600



Rectifier diode  
ultrafast, low switching loss

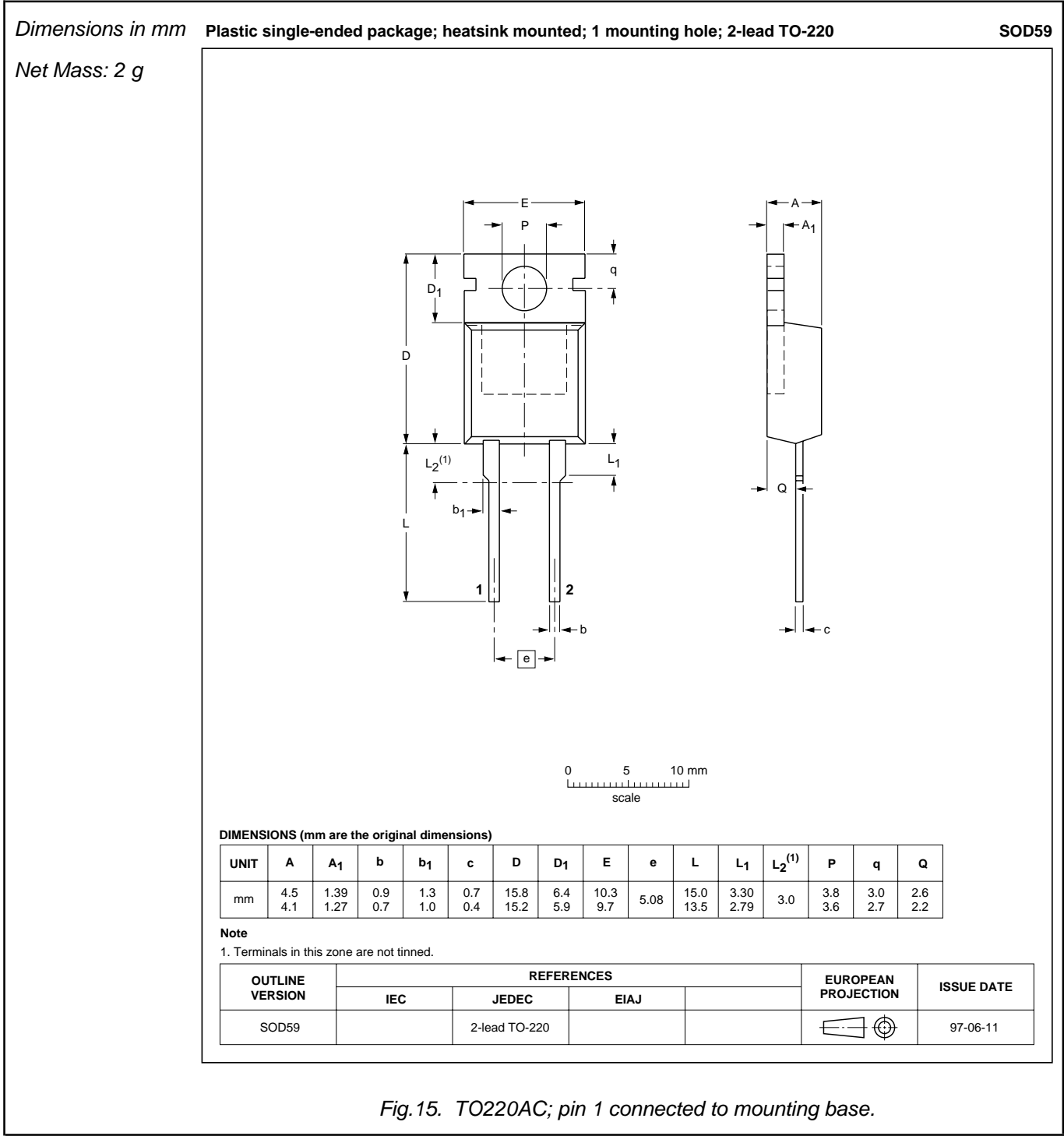
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Rectifier diode  
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MECHANICAL DATA



Notes

- 1. Refer to mounting instructions for TO220 envelopes.
- 2. Epoxy meets UL94 V0 at 1/8".

# Rectifier diode ultrafast, low switching loss

BYC5-600

## DEFINITIONS

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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